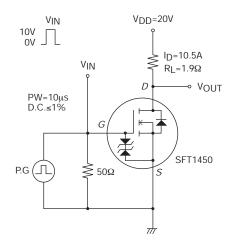
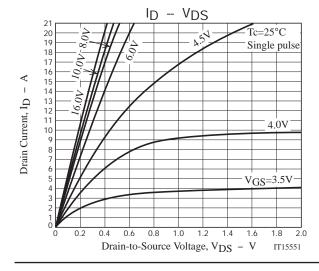
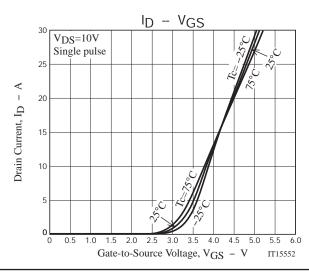
Electrical Characteristics at Ta=25°C

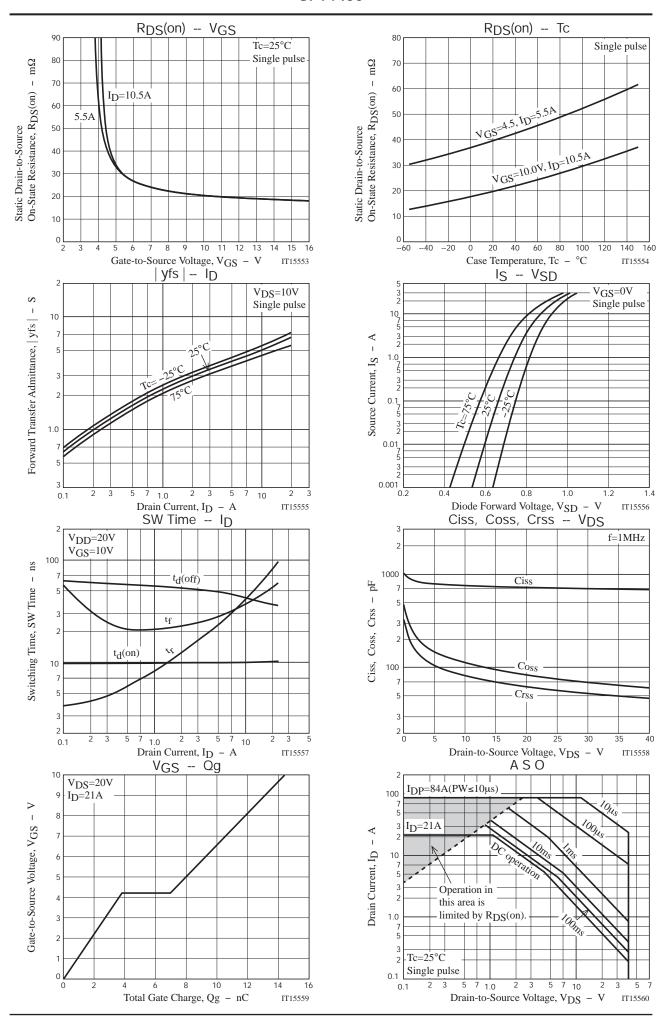
Parameter	Symbol	Conditions	Ratings			Unit
			min.	typ.	max.	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	40			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =40V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.7		2.6	٧
Forward Transfer Admittance	yfs	VDS=10V, ID=10.5A		5.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =10.5A, V _{GS} =10V		21	28	mΩ
	R _{DS} (on)2	I _D =5.5A, V _G S=4.5V		40	56	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		715		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		85		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		65		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		10		ns
Rise Time	t _r	See specified Test Circuit.		42		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		42		ns
Fall Time	tf	See specified Test Circuit.		38		ns
Total Gate Charge	Qg	V _{DS} =20V, V _{GS} =10V, I _D =21A		14.4		nC
Gate-to-Source Charge	Qgs	V _{DS} =20V, V _{GS} =10V, I _D =21A		3.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =20V, V _{GS} =10V, I _D =21A		3.1		nC
Diode Forward Voltage	VSD	IS=21A, VGS=0V		0.96	1.2	V

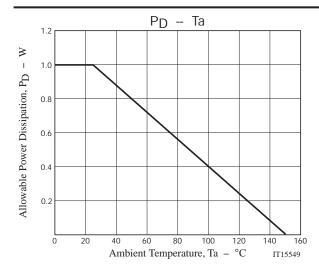
Switching Time Test Circuit

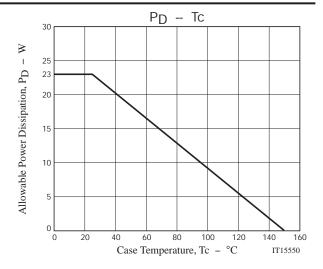












Note on usage: Since the SFT1450 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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